

NP05-11449-2E

32 Mbit Mobile FCRAM[™] 3.0 V, Page Mode MB82DP02183E-65L

■ FEATURES

- Pseudo SRAM with Asynchronous SRAM Interface
- 8 Words Page Read Access Capability
- Byte Control by \overline{LB} , \overline{UB}
- · Low Power Consumption
- · Various Power Down Mode
 - Sleep
 - 4 Mbit Partial
 - 8 Mbit Partial
- · Chip / Wafer Business



| Part Number | | MB82DP02183E-65L |
|---------------------------------|-------|-------------------|
| Organization | | 2 M Word × 16 bit |
| Supply Voltage | | 2.6 V to 3.1 V |
| Page Address Access Time (Max.) | | 20 ns |
| Address Access Time (Max.) | | 65 ns |
| Active Current (Max.) | | 30 mA |
| Standby Current (Max.) | | 120 μΑ |
| Power Down Current (Max.) | Sleep | 10 μΑ |

Note: FCRAM is a trademark of Fujitsu Limited, Japan.